

INTEGRATED DC-DC CONVERTERS USING THIN-FILM MAGNETIC POWER INDUCTORS

DE-SC0009200

11/15/2012 THROUGH 05/14/2015

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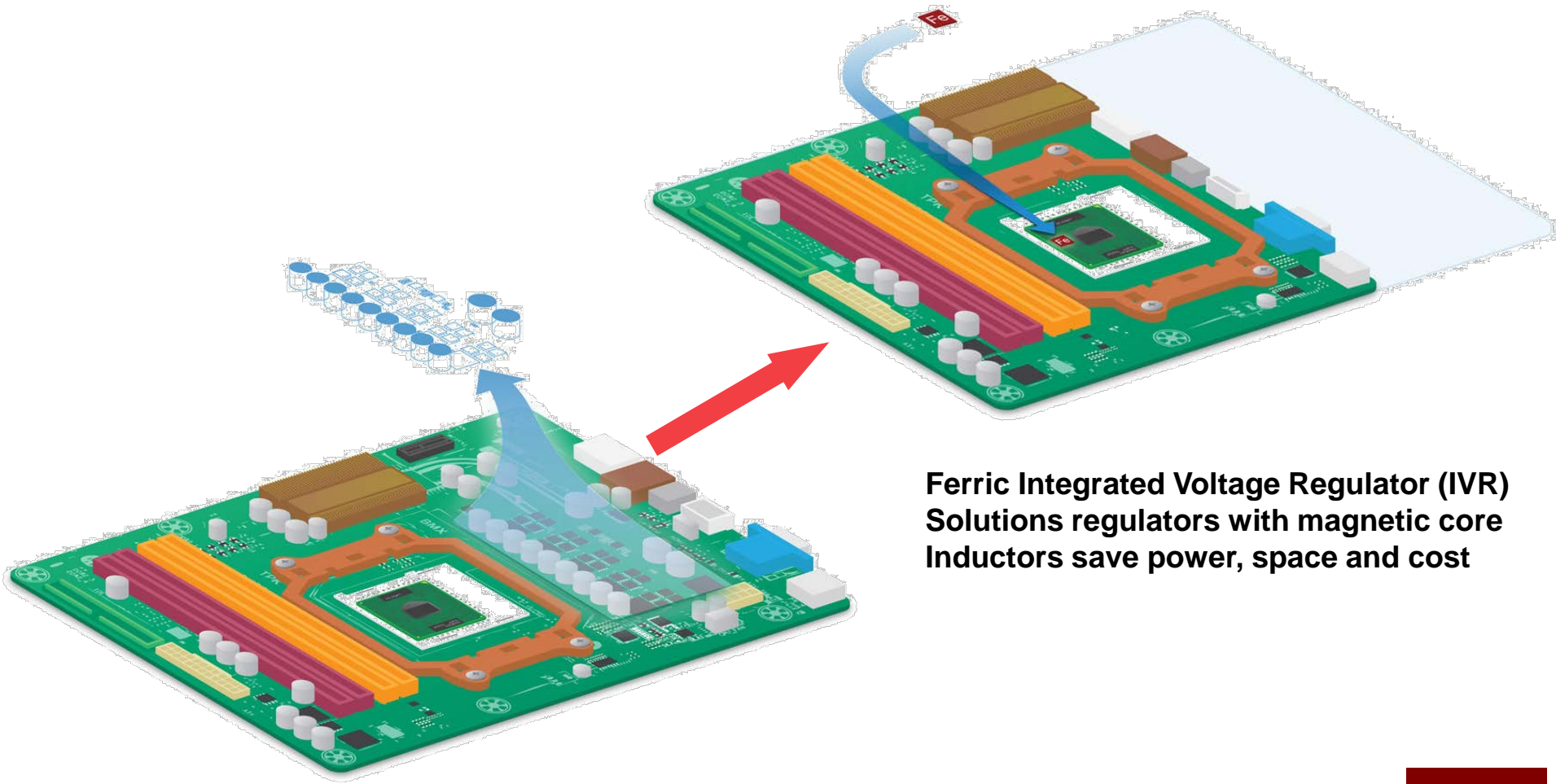
U.S. DOE Advanced Manufacturing Office Program Review Meeting

Washington, D.C.

June 14-15, 2016

FERRIC TECHNOLOGY

On-chip Magnetic Thin-Film Inductors Save Power, Space And Cost

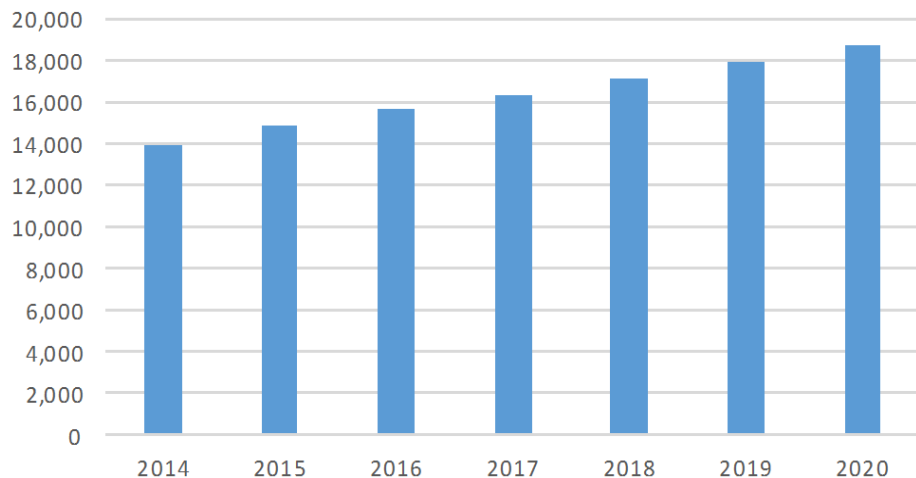


Ferric Integrated Voltage Regulator (IVR) Solutions regulators with magnetic core Inductors save power, space and cost

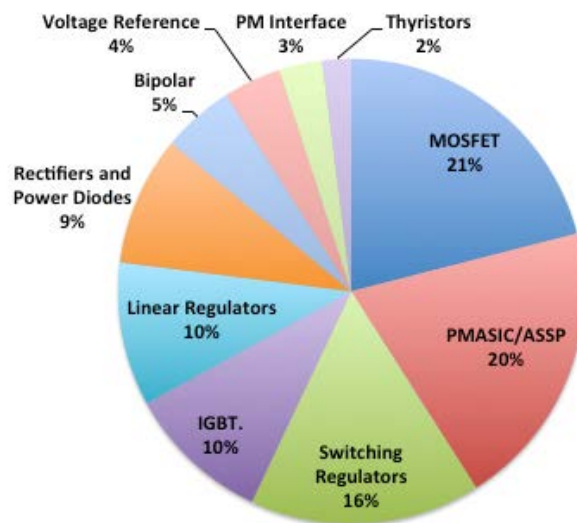
FERRIC IS ADDRESSING THE \$15B/YR SWITCHING VOLTAGE REGULATORS MARKET

- Worldwide market for Power Electronic products growing to \$50B in 2020
- Market for Switching Voltage Regulators is growing to be 18-20% of Power Management market: forecast to be more than \$18B in 2020

Voltage Regulator Market (USD Million)



Worldwide Power Management Semiconductor Market Share Forecast by Device (2010 Percentage Share Revenue in US Dollars)



Source: Ohr, S. (2015). Competitive Landscape: Standard Power Management IC Vendors, Worldwide, 2015, Gartner.



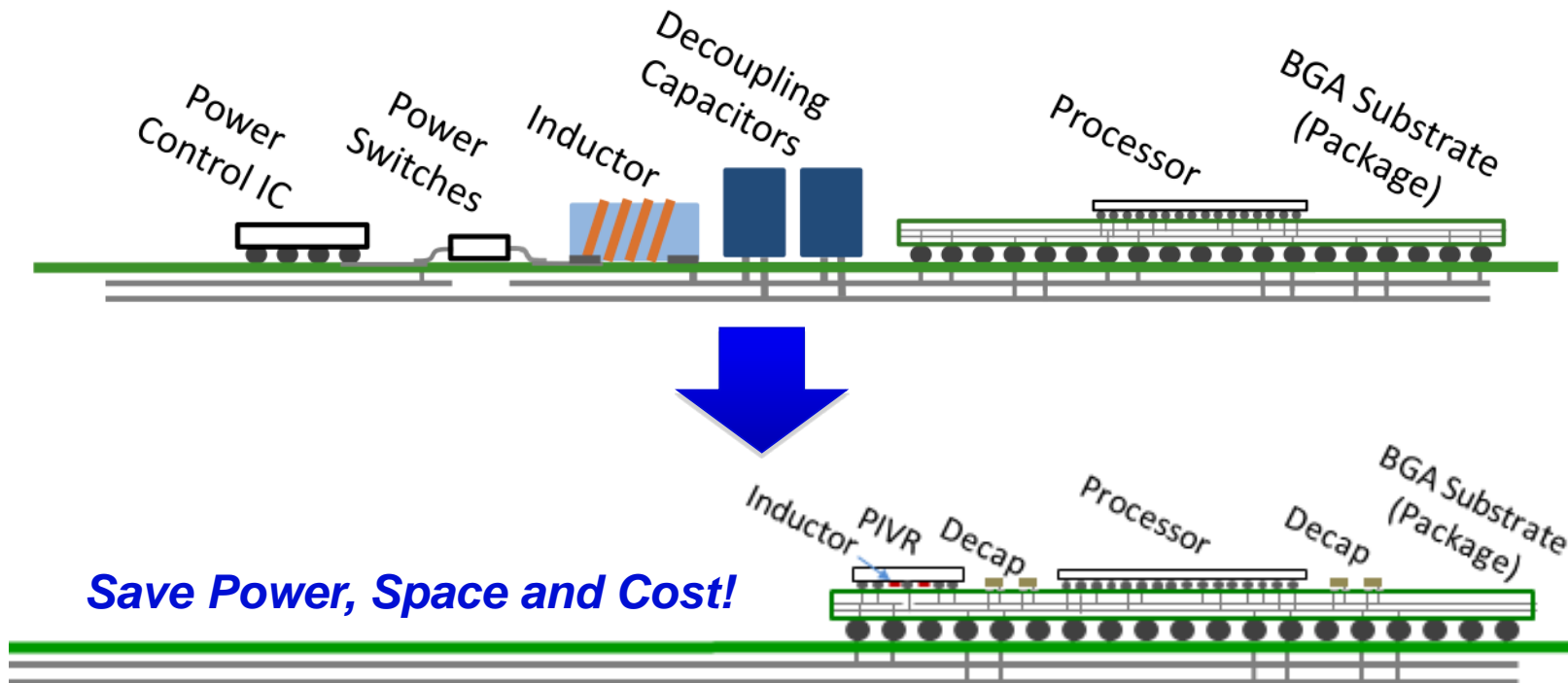
FERRIC

THE COMPANY

- Fabless semiconductor technology company, founded in 2011
 - Located in New York City
- Integrated magnetic component and power conversion technology
- Licensing partnership with TSMC
- Team expertise:
 - semiconductor device manufacturing
 - magnetic thin-films
 - RF device design, characterization and modeling
 - CMOS IC design for power conversion applications
- Chip Sales, Design IP and Process Licensing

INTEGRATED VOLTAGE REGULATION

- High power density ($10\text{W}/\text{mm}^3$) low voltage ($< 12\text{V}$) DC-DC converters
- Reduce I^2R losses associated with high current levels in microprocessors board + socket + package
- Enable delivery of many independently scalable supplies, taking advantage of power savings from fine-grain DVFS



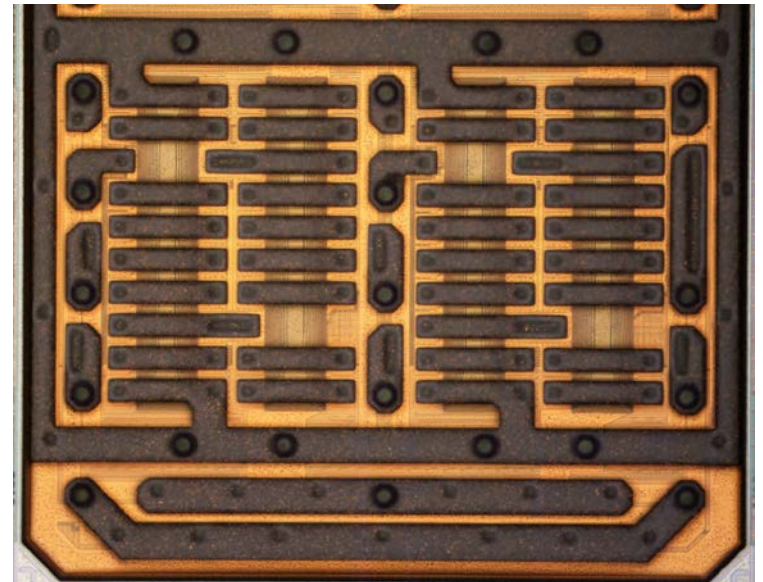
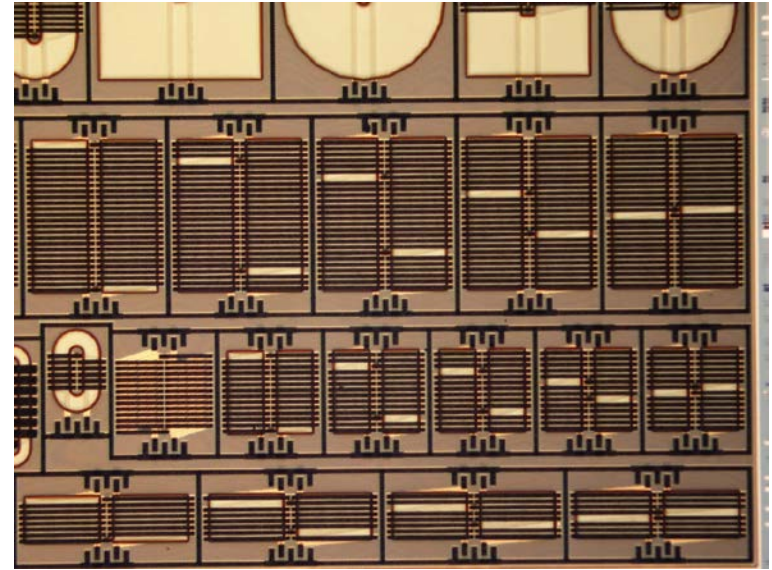
FERRIC TECHNOLOGY ELEMENTS

■ Integrated Inductors

- Inductance density
 - $> 300\text{nH}/\text{mm}^2$, $> 8,500\text{nH}/\text{mm}^3$
- Current density $> 12\text{A}/\text{mm}^2$
- DC Resistance $< 100\text{m}\Omega$
- Magnetic Coupling $k > 0.95$

■ Integrated Circuit Designs

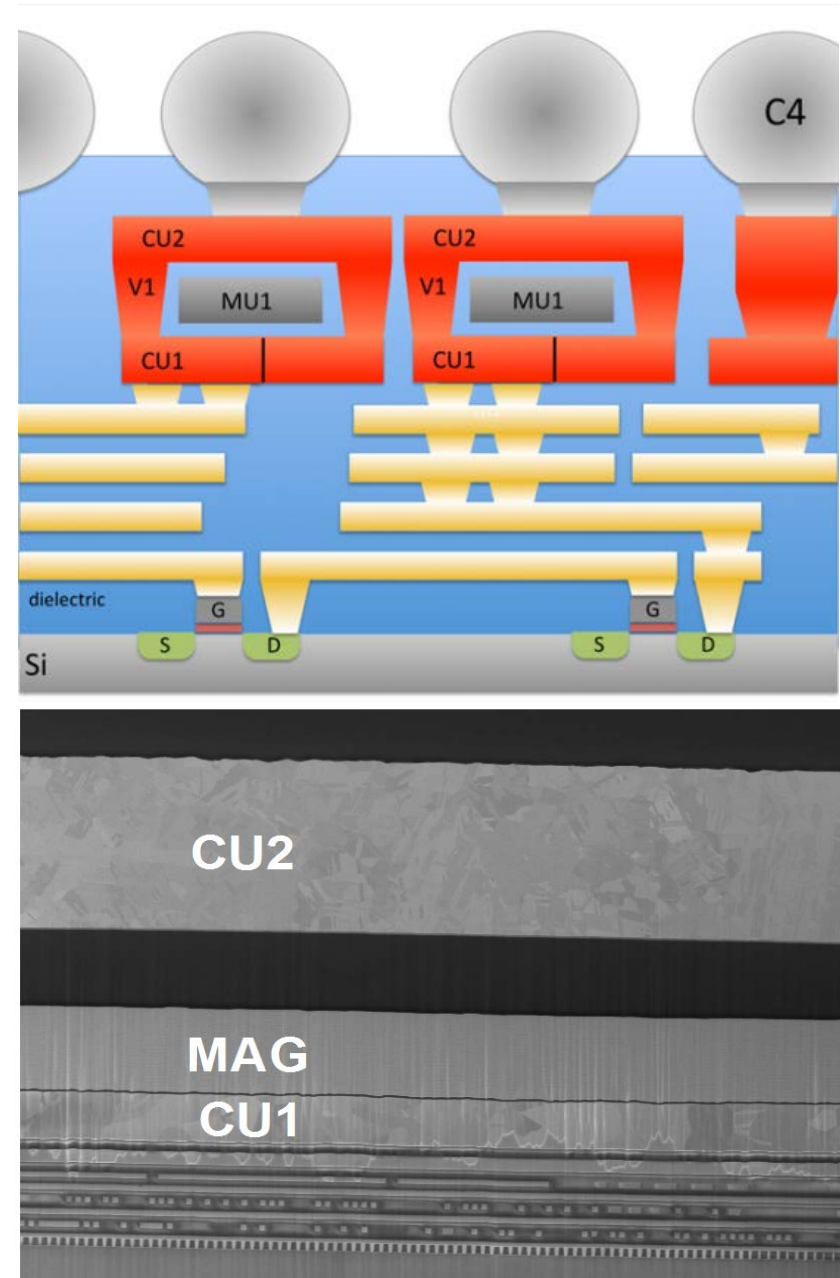
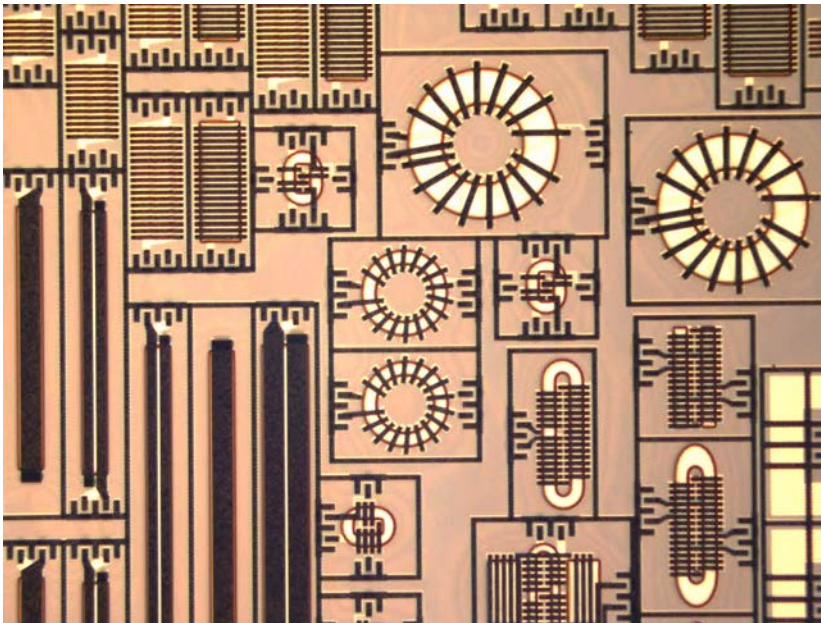
- High switching frequency
- High bandwidth controller
- Optimization for high efficiency
- Optimization for high density



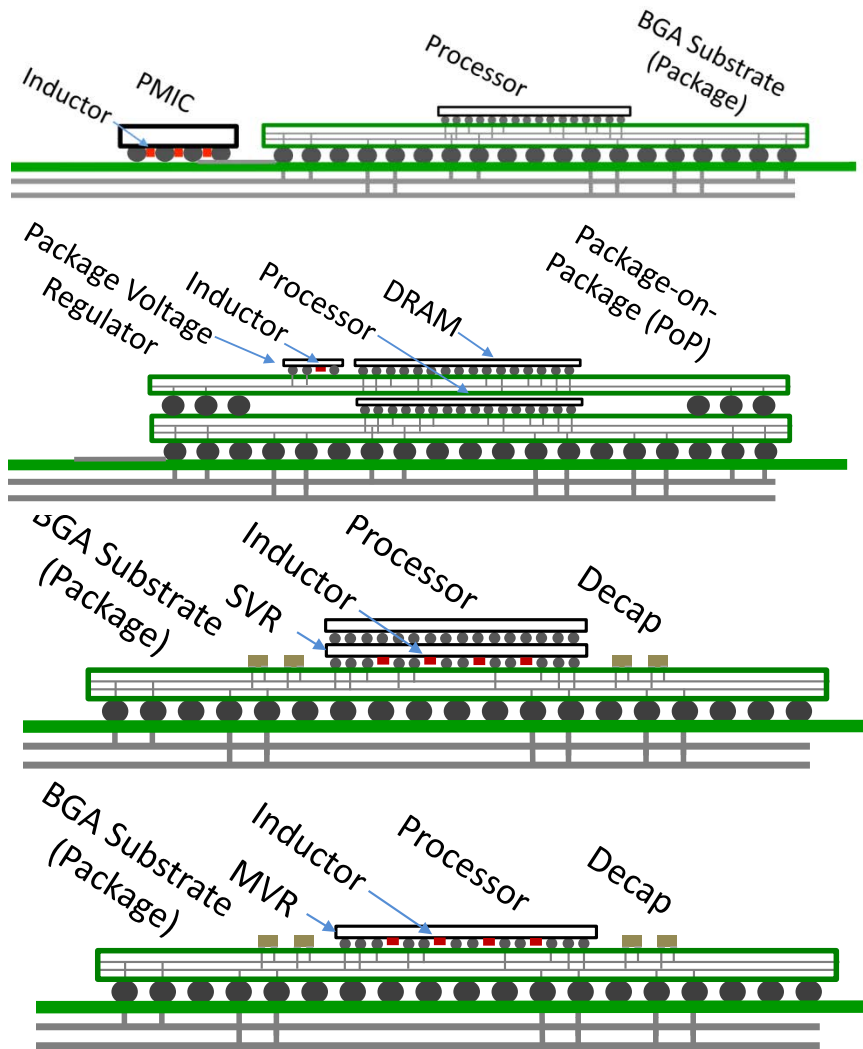
FERRIC INDUCTORS

Ferric CMOS integrated magnetic thin-films enable high-quality, high density, low-profile on-chip/on-package inductive components

- Proven Technology
- Integrated with Standard CMOS Flow
 - Inductor layers available as BEOL process option (similar to MIM)
 - Circuit models, LVS, DRC



FERRIC TECHNOLOGY | PRODUCT IMPLEMENTATION



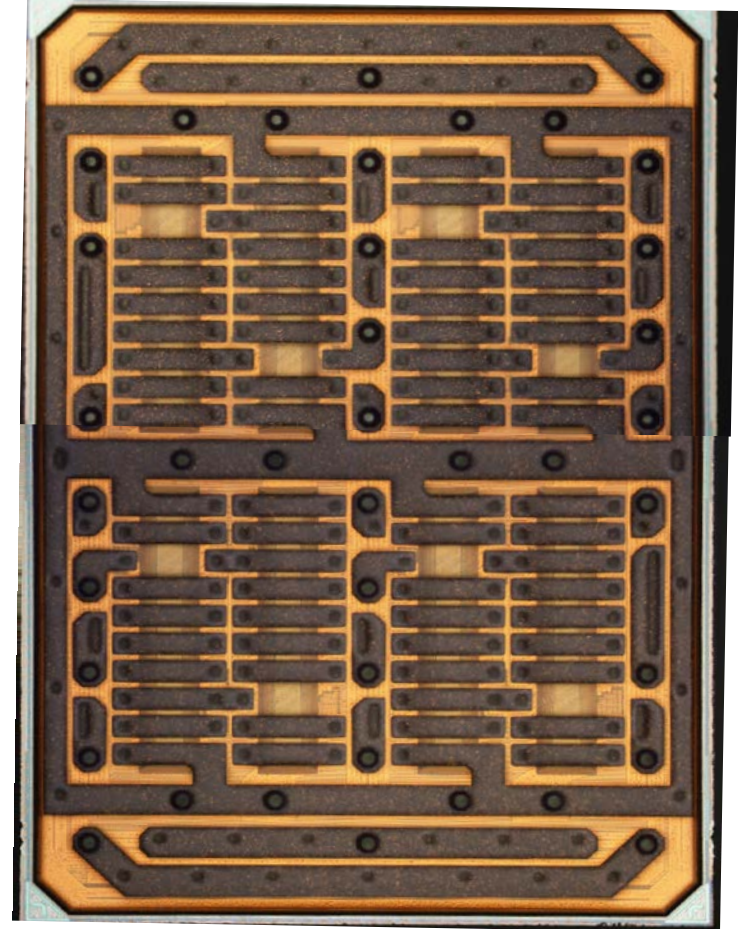
- Power Management IC (**PMIC**)
- Package Integrated Voltage Regulators (**PVR**)
- Interposer or IPD Voltage Regulator
- Monolithic Integrated Voltage Regulator (**MVR**)

FERRIC CIRCUITS

Ferric thin-film power inductors integrated with TSMC CMOS enable efficient, high density on-chip/on-package DC-DC power conversion

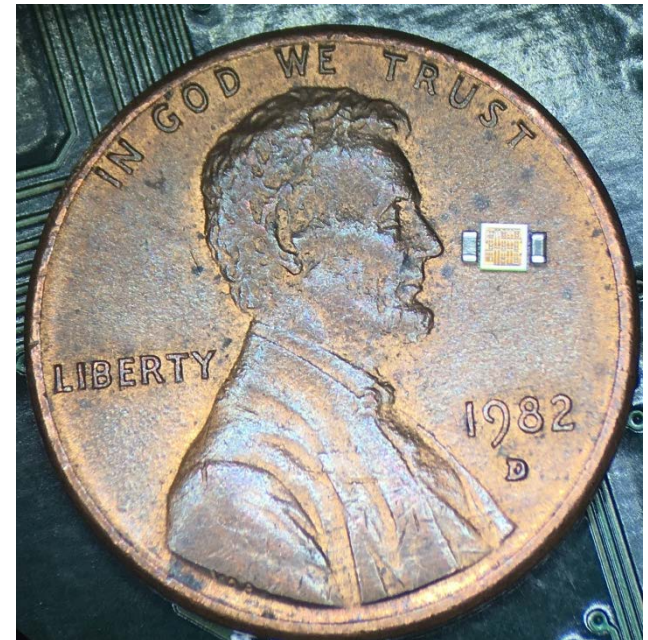
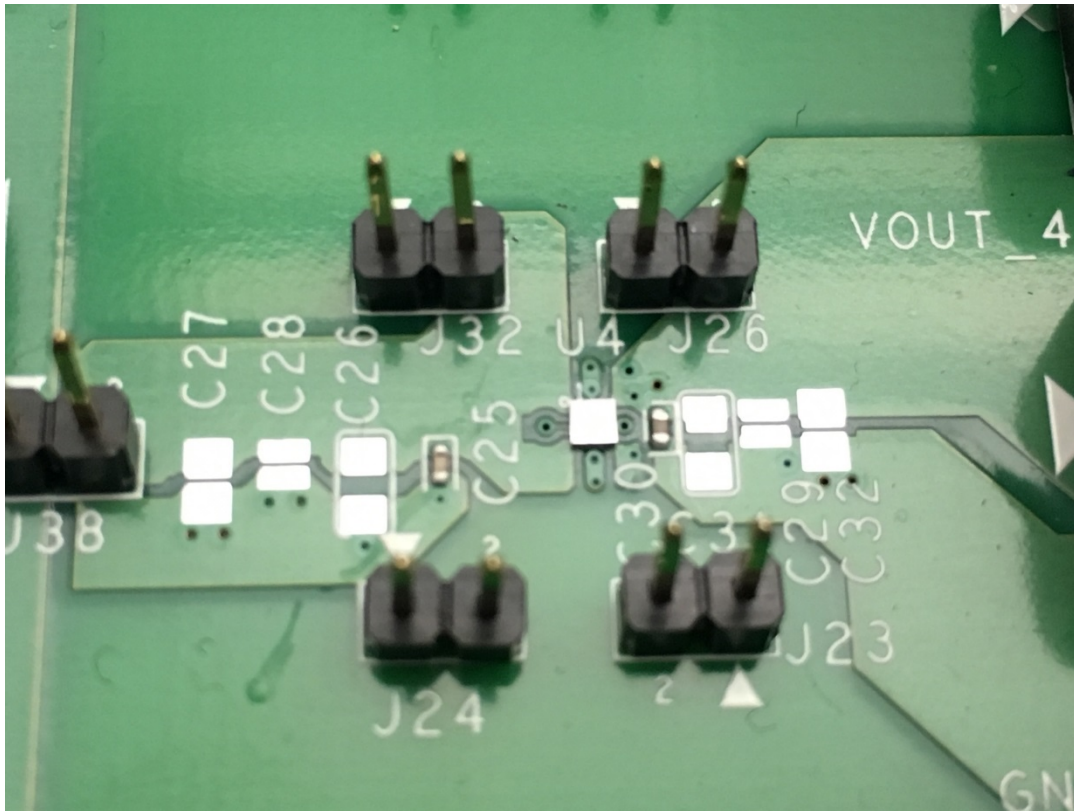
Provides multiple options for true Point-of-Load power conversion for ICs

- Improve voltage regulation (broadband power supply impedance as-low-as $500\mu\Omega$)
- Improved energy efficiency with enhanced power management (DVFS and reduced DC power margins)
- Reduced current levels in upstream PDN (board, socket, package)
- Reduced board-level power conversion BOM and area



FERRIC CIRCUITS / BOOST CONVERTER

- Total Solution Size: 2.5mm²
 - 1x Dachshund Chip (1x 1.5mm²)
 - 2x 0402 Discrete Capacitors (2x 0.5mm²)



PROJECT MANAGEMENT & BUDGET

- This development project has been active since 2013 and will continue until Ferric IVR technology sees wide scale commercial adoption
- U.S. Department of Energy (DE-EE0002892)

Milestone	Timeframe	Financing Approach	Received/Anticipated funding
A. Magnetic thin-film process development on large wafers	Q1–Q2'13	DOE SBIR Phase I	150,000
B. Development of PVR products with integrated magnetic inductors	Q3'13 – Q3'16	NSF SBIR Phase II	750,000
C. Technology transfer to major foundry	Q3'14 – Q2'16	Venture Capital	500,000
		DOE SBIR Phase II	750,000
D. Development and Qualification of advanced IVR circuits and systems	Q2'14 – Q3'16	Venture Capital	1,000,000
		NSF SBIR Phase IIB	750,000
E. Development, Productization and marketing of PVRs, IPDs and other technology implementations	Q2'16 – Q4'18	Venture Capital,	3,000,000
		DOE SBIR Phase IIB	1,000,000